NSN 5962-01-283-9168

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View Online at https://aerobasegroup.com/nsn/5962-01-283-9168

view Offilite at https://defobasegroup.com/his//0302-01-200-3100
Body Length:
Between 1.235 inches and 1.290 inches
Body Width:
Between 0.510 inches and 0.600 inches
Body Height:
Between 0.140 inches and 0.180 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
High performance and schottky and high speed and high reliability and multichip and low power and 3-state output and monolithic and
bipolar and electrostatic sensitive and hermetically sealed and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Current Rating Per Characteristic:
185.00 milliamperes supply
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Capitance Rating Per Characteristic:
12.00 output picofarads
Time Rating Per Chacteristic:
55.00 nanoseconds access
Memory Device Type:
Prom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit

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N/a

Shelf Life:

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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